NSN 5961-01-258-4756

Yes - demil/mli

Fiig: A110a0

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-258-4756 **Inclosure Material:** Glass and metal **Overall Length:** 1.125 inches **Overall Diameter:** 0.437 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 32.0 reverse voltage, instantaneous **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** 2 insulated wire leads, one green and one white and green; photodiode well; photodiode holder; insulation **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**